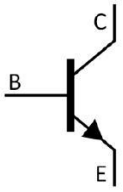
SOT-323 NPN Silicon NPN transistor in a SOT-323 Plastic Package.

BC858W

High current, low voltage complementary pair with BC858W.

General purpose switching and amplification.

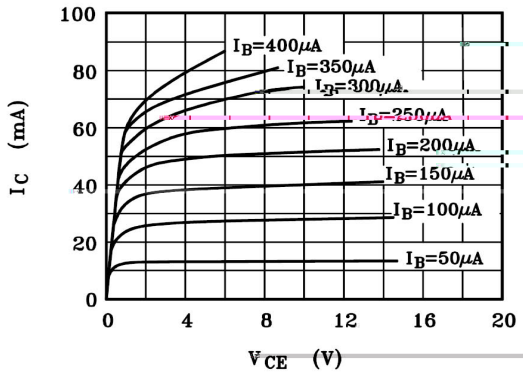


PIN1 Emitter PIN 2 Base PIN 3 Collector

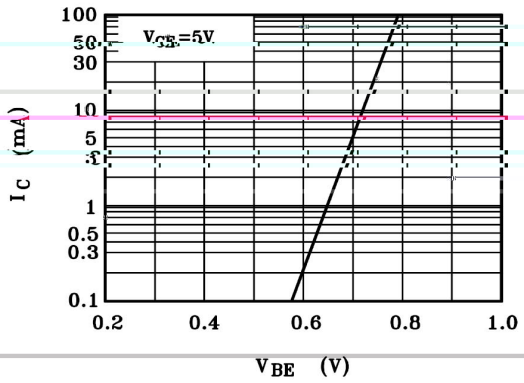
h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	110 220	200 450	420 800
Marking	H1J	H1K	H1L

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current- Continuous	I_C	100	mA
Peak Collector Current - Continuous	I_{CM}	200	mA
Collector Power Dissipation	P_C	200	mW

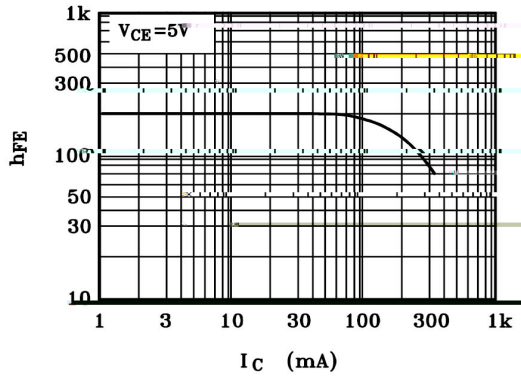
I_C – V_{CE}



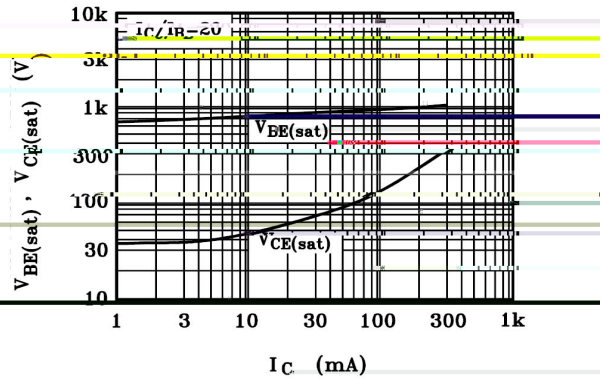
I_C – V_{BE}



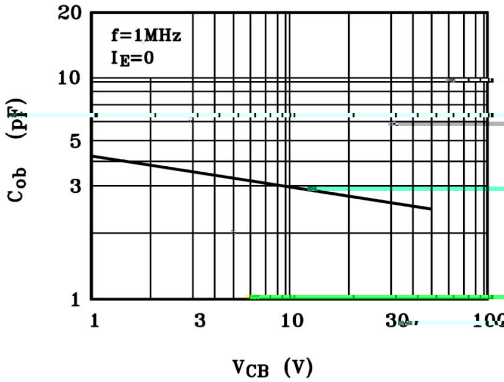
h_{FE} – I_C

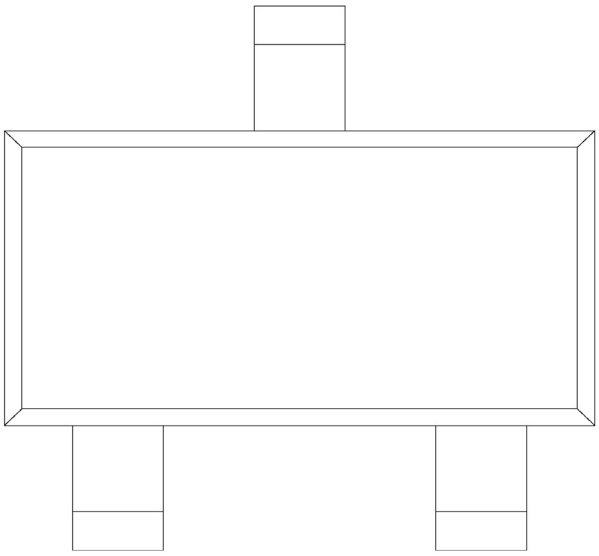


$V_{BE(sat)}$, $V_{CE(sat)}$ – I_C



C_{ob} – V_{CB}



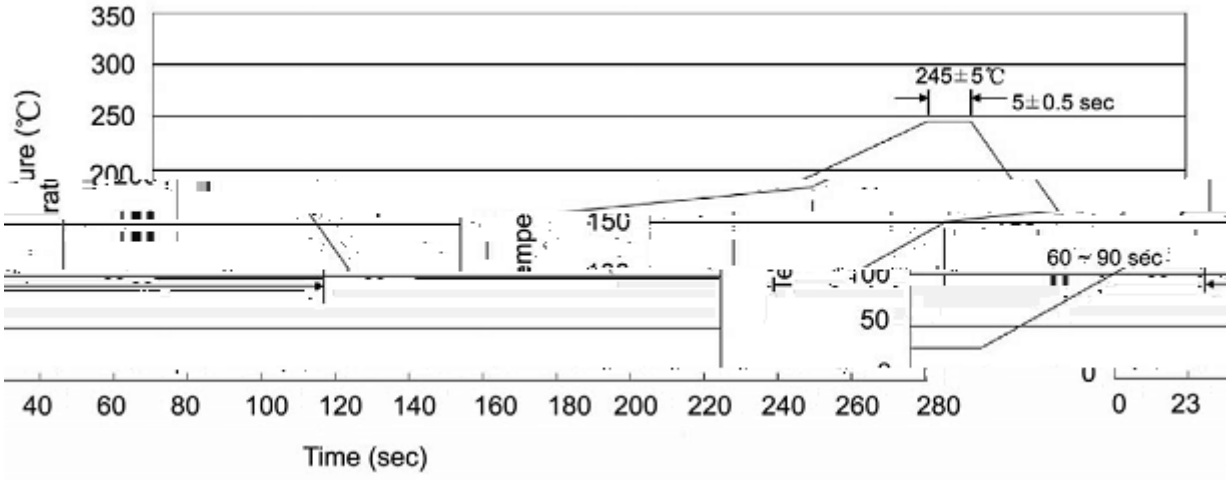


H

1J

Note:

H: Note(5)Tuctions Tf5284



Note:

1 25 150 60 90sec;

2 245±5 5±0.5sec;

3 2 10 /sec.

1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:245±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

260±5 10±1 sec.

Temp.:260±5 Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-323	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205